Memory Selection Guidelines for High Performance Computing with Dell™ PowerEdge™ 11G Servers

A Dell Technical White Paper

By Garima Kochhar and Jacob Liberman

High Performance Computing Engineering
Dell Product Group

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Executive Summary
High Performance Computing Clusters (HPCCs) link together commodity servers with high-speed networks in order to achieve supercomputer-like performance. Dell’s 11th Generation (11G) PowerEdge servers are suitable building blocks for HPCC due to the excellent price for performance they can deliver. However, architectural enhancements to the 11G memory subsystem can complicate cluster design. This paper provides memory subsystem design recommendations for optimizing 11G servers as HPCC nodes. These recommendations are based on the measured performance and power consumption of clusters and individual servers running a suite of common High Performance Computing (HPC) applications. Comparisons are made between memory controller frequencies, DIMM types, DIMM frequencies, and DIMM population schemes. The measured results demonstrate that the theoretical differences between memory subsystems do not translate directly into improved performance. Memory subsystem design decisions must be based on measured application data rather than theoretical results or synthetic benchmarks. The paper concludes with memory selection guidelines for optimizing performance, energy efficiency, or value.
**Introduction**

High Performance Computing Clusters (HPCCs) link together commodity servers with high-speed networks in order to achieve supercomputer-like performance. Dell’s 11\textsuperscript{th} Generation (11G) PowerEdge servers are suitable building blocks for HPCC due to the excellent price for performance they can deliver. 11G servers feature Double Data Rate-3 (DDR-3) SDRAM, Second Generation PCI-E expansion slots, and Intel® Xeon® 5500 series processors\textsuperscript{1}. Xeon 5500 series processors are based on the Nehalem-EP micro-architecture, the latest revision of the Intel Xeon processor family. Nehalem-EP’s memory subsystem is fundamentally different than those of its predecessors. With Nehalem-EP, Intel abandoned the Front Side Bus architecture in favor of memory controllers integrated directly onto the processors. Nehalem-EP also supports a broad range of memory configurations that include new DIMM types, additional DIMM speeds, and several DIMM population schemes that can affect performance. This modular design allows users to select memory subsystem components tailored to specific needs such as maximizing performance, expandability, or energy efficiency. However, it also complicates server design for those who are unsure how their choices will affect the systems.

This paper provides memory subsystem design recommendations for optimizing 11G servers as HPCC nodes. The recommendations are based on the measured performance and power consumption of clusters and individual servers running a suite of common High Performance Computing (HPC) applications. Comparisons are made between memory controller frequencies, DIMM types, DIMM frequencies, and DIMM population schemes. This paper begins with an overview of the Intel Nehalem micro-architecture with a focus on the memory subsystem, then details the test methodology and performance impact of the various memory options across typical HPC workloads and concludes with memory selection guidelines derived from the performance results.

**PowerEdge 11G Memory Overview**

Xeon 5500 series processors have DDR-3 memory controllers integrated directly on the processor chips. DDR3 SDRAM\textsuperscript{2} is a random access memory technology used for high bandwidth storage. DDR3 supports twice the bandwidth rate of its predecessor – DDR2 – without a latency increase. DDR3 also supports higher capacities and lower power consumption than DDR2. Each Xeon 5500 processor socket has three DDR3 SDRAM channels. 11G servers support two or three DIMMS per channel, depending on the server model.

Accesses to the memory channel directly connected to the processor are called “local”. Access to the memory channels connected to the other processor are called “remote”. Remote accesses traverse a high-speed bus between the sockets called the Quick Path Interconnect (QPI) link. Local accesses are faster than remote accesses, which makes Nehalem-EP a Non-Uniform Memory Access (NUMA) architecture. Figure 1 depicts the Nehalem-EP memory subsystem layout. On the Xeon 5500

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\textsuperscript{1} The Nehalem-EP architecture is based on the Intel Xeon processor family.

\textsuperscript{2} DDR3 SDRAM is a memory technology that provides high bandwidth storage.

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**Figure 1 – Nehalem-EP block diagram**

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series, the processor clock frequency determines the maximum bandwidth of the integrated memory controller. The theoretical differences between local and remote memory bandwidths by processor type are described in Table 1.

Table 1 - Theoretical Memory Bandwidth

<table>
<thead>
<tr>
<th>CPU GHz</th>
<th>QPI Link</th>
<th>Mem._CTL</th>
<th>QPI BW</th>
</tr>
</thead>
<tbody>
<tr>
<td>2.66 - 3.20</td>
<td>6.40 GT/s</td>
<td>31.99 GB/s</td>
<td>25.60 GB/s</td>
</tr>
<tr>
<td>2.26 - 2.53</td>
<td>5.86 GT/s</td>
<td>25.58 GB/s</td>
<td>23.44 GB/s</td>
</tr>
<tr>
<td>1.86 - 2.13</td>
<td>4.80 GT/s</td>
<td>19.20 GB/s</td>
<td>19.20 GB/s</td>
</tr>
</tbody>
</table>

This table points out that remote memory accesses are slower than local accesses on NUMA architectures. HPC users should enforce policies where processes only access local memory whenever possible. For local applications running in Linux, this can be done with the `numactl` utility. For distributed memory applications, CPU and memory affinity can be enforced through MPI runtime parameters.

There are two situations where remote memory accesses are unavoidable. First, processes that require more memory than what is available to a single processor. Second, processes that spawn more threads than available cores within the local socket. CPU and memory affinity are not appropriate in either case. 11G servers have a BIOS feature called *Node Interleaving* that stripes data across both memory controllers when enabled. Interleaved accesses are slower than local-only accesses because every other operation traverses the QPI link. However, this feature prevents the worst case scenario where a process is forced to access remote memory at every operation. Additional 11G BIOS features are described in the Dell HPC engineering whitepaper entitled *Optimal BIOS Settings for High Performance Computing with PowerEdge 11G Servers*.

11G servers are not only based on a new micro-architecture, they also allow users to select new DIMM types, speeds, and population schemes. 11G servers support two types of DDR3 SDRAM – Unbuffered Dual Inline Memory Modules (UDIMMs) and Registered Dual Inline Memory Modules (RDIMMs). Both DIMM types will be discussed in greater detail in subsequent sections. RDIMMs and UDIMMs both support DIMMs of varied capacities further complicating the choice. At the time of writing, the maximum supported memory capacity per DIMM is 16GB for RDIMMs but only 2GB for UDIMMs. The Xeon 5500 series memory controller operates at speeds of 800, 1066 or 1333 MHz depending on processor model, DIMM speed, and DIMM population.

11G servers offer a modular memory sub-system design that encourages users to select components tailored to their workloads. However, the additional choices afforded by the architecture can complicate the server design process. Users who may be accustomed to selecting RAM solely based on capacity are confronted with considerations that affect performance and energy efficiency. In the following sections, this paper compares these choices and establishes recommendations for HPC workloads.

**Test Methodology**

Intel Xeon 5500 based servers add an extra layer of complexity to the memory sub-system by providing a variety of choices. This paper quantifies these choices in order to derive guidelines for maximizing performance and energy efficiency in an HPC context. To do this, each memory configuration was
compared across several dimensions. These dimensions include theoretical performance, measured micro-benchmark performance, single node application performance, and, in some cases, cluster level application performance. This study follows this approach for several reasons.

First, the difference between theoretical and micro-benchmark performance indicate the efficiency of the sub-system in question. If the theoretical and micro-benchmark performance results are equal, the subsystem is perfectly efficient. This is almost never the case.

Second, micro-benchmark results do not directly translate into application performance gains. The theoretical results set the boundaries for the micro-benchmark results which, in turn, do the same for application performance. For example, if the micro-benchmark results show a 20% performance increase across memory types, the application performance will improve by less than 20%, if at all. With a few exceptions, distributed memory application performance gains will be bounded by the increase observed on single nodes. This is shown graphically in Figure 2. Exceptions to this statement include super-scalar performance induced by cache coalescing and embarrassingly parallel applications where cluster performance scales linearly with single node performance.

Single servers and clusters were benchmarked using a suite of typical HPC applications and micro-benchmarks. A mix of open source and commercial applications were chosen for the study. Details of the benchmarks are provided in Appendix C – Benchmark Descriptions

Performance Evaluation

This section describes the results of the performance and energy efficiency tests conducted on the clusters and single servers. Each test includes micro-benchmark and application performance measurements. The micro-benchmarks used in this study measure memory performance in terms of bandwidth and latency. Bandwidth measures the rate at which memory can be moved across the bus. Latency measures the time it takes to initiate a zero size message transfer. The total time for a memory transfer operation can be calculated with the following formula:

\[ \text{Time} = \text{Latency} + (\text{Message Size} / \text{Bandwidth}) \]

Both metrics are important for evaluating memory subsystem performance. High bandwidth minimizes the time needed to transfer large data sets. Low latency minimizes the time required to process many
small transactions. Memory bandwidth and latency measurements are supplemented by processor micro-benchmark results that measure the rate at which the system can solve floating point operations.

Application performance is measured across a range of HPC applications at both the single server and cluster levels. In order to compare performance across applications, performance results are converted to a ‘rating’ that specifies the number of times the application can be run per day. A lower run time translates to a higher rating. Energy efficiency is measured as performance divided by power consumed. All results were gathered in Dell’s HPCC engineering lab. The test cluster configuration is described in Appendix B – Test Cluster. Specific configuration details for each benchmark are also noted where appropriate.

The following sections examine the impact of the different DIMM types, DIMM frequencies and DIMM population schemes on the performance of the system while taking power consumption into account as well.

HPC workloads require balanced architectures where no individual subsystem dominates execution time. These performance guidelines may be inappropriate for enterprise workloads such as databases or mail servers.

**Memory Type: UDIMMs versus RDIMMs**

11G servers support two types of DDR3 SDRAM – Unbuffered Dual Inline Memory Modules (UDIMMs) and Registered Dual Inline Memory Modules (RDIMMs). 11G servers support UDIMMs and RDIMMs of both 1333 and 1066 MHz frequencies. The primary differences between UDIMMs and RDIMMs are:

- RDIMMs have a register used as a pass through for address and command signals. This allows servers to support more RDIMMs per channel than UDIMMs.
- RDIMMs consume more power than UDIMMs but are available in larger capacities and higher ranks.
- RDIMMs also provide additional data protection and reliability features.

At the time of writing, RDIMMs were available up to 16GB in capacity and quad-rank while UDIMMs were available up to 2GB and dual rank. 11G servers support up to 2 UDIMMs per channel versus up to 3 RDIMMs per channel.

Figure 3 shows RDIMM performance relative to UDIMM performance on four single server HPCC application benchmarks. Values higher than 1.0 indicate RDIMMs outperformed UDIMMs by that amount.
Figure 3 – Single server RDIMM vs. UDIMM performance, PowerEdge R610, Dual Intel Xeon X5570, 6 * 4GB 1066MHz RDIMMs and UDIMMs

Figure 3 shows that the performance difference between UDIMMs and RDIMMs was within 4% across all benchmarks. Benchmarks that are not bandwidth sensitive – such as HPL – performed within 1% across DIMM types. Eclipse is a bandwidth sensitive benchmark, but it’s performance improved by only 2% across DIMM types. Ansys Mechanical V12cg-3, where UDIMMs were 4% faster than RDIMMs, is not statistically significant as this improvement is within the variation between multiple runs of the same job.

Table 2 compares server power consumption across these DIMM types during the benchmark tests. RDIMMs consume 2.4W to 5.2W more per DIMM. UDIMMs are more energy efficient than RDIMMs by 4-10% on HPC applications.

Table 2 – RDIMM and UDIMM power consumption

<table>
<thead>
<tr>
<th>Benchmark</th>
<th>RDIMM power</th>
<th>UDIMM power</th>
<th>Power delta per DIMM</th>
</tr>
</thead>
<tbody>
<tr>
<td>Ansys Mechanical - V12sp5</td>
<td>308.15 W</td>
<td>291.90 W</td>
<td>2.71 W</td>
</tr>
<tr>
<td>Eclipse - FOURMILL</td>
<td>319.34 W</td>
<td>287.89 W</td>
<td>5.24 W</td>
</tr>
<tr>
<td>HPL</td>
<td>322.58 W</td>
<td>308.15 W</td>
<td>2.41 W</td>
</tr>
<tr>
<td>Fluent – truck_poly_14m</td>
<td>319.41 W</td>
<td>294.72 W</td>
<td>4.11 W</td>
</tr>
</tbody>
</table>
At 1 DIMM per channel and equal capacities, RDIMM and UDIMM performance is within 2% for most HPC applications. On a cluster – where communication overhead and application scalability are the largest bottlenecks – the performance difference would be smaller. RDIMMs also consumed between 4 and 10% more power than UDIMMs during the energy efficiency benchmarks. Therefore, for the same memory capacity, UDIMMs are recommended for HPC clusters over RDIMMs due to the savings in power. RDIMMs must be used when UDIMMs cannot meet the necessary memory capacity or when RAS features are required. Data protection features such as mirroring entail significant performance overhead and are not recommended for HPC customers.

Memory Frequency: 1066 versus 1333
11G servers support 1066 MHz and 1333 MHz DDR-3 SDRAM. The memory frequency, at which the system operates, however, is determined by a minimization function of three factors:

1) DIMM frequency
2) Memory controller speed
3) Channel population scheme

System memory speed = MIN (Memory Controller speed, DIMM frequency, population)

First, the operating memory speed is dictated by the DIMM frequency. 1066 MHz DIMMs cannot run at 1333 MHz, but 1333 MHz and 1066 MHz can both run at lower frequencies. Different speed memory DIMMs should not be mixed within the same server.

Memory controller speed is limited by the processor type. Xeon 5500 ‘X’ series processors run at a maximum speed of 1333 MHz. ‘L’ and ‘E’ series processors run at either 1066 or 800 MHz depending on the CPU clock frequency.

Finally, memory population rules dictate that 1 DIMM-Per-Channel (DPC) or 2 DPC can run at either 1066 or 1333 MHz, depending on server model and DIMM type. Populating 3 DPC will force the operating memory speed to 800 MHz. These factors are summarized in Table 3.

Table 3 – System Memory Speed

<table>
<thead>
<tr>
<th>System Operating Speed</th>
<th>Memory controller speed</th>
<th>DIMM speed</th>
<th>DIMM population</th>
</tr>
</thead>
<tbody>
<tr>
<td>1333 MHz</td>
<td>1333 MHz</td>
<td>1333MHz</td>
<td>1 or 2 DPC</td>
</tr>
<tr>
<td>1066 MHz</td>
<td>1066 MHz</td>
<td>1066 or 1333 MHz</td>
<td>1 or 2 DPC</td>
</tr>
<tr>
<td></td>
<td>1333MHz</td>
<td>1066MHz</td>
<td>1 or 2 DPC</td>
</tr>
<tr>
<td>800 MHz</td>
<td>800 MHz</td>
<td>1066 or 1333 MHz</td>
<td>1, 2 or 3 DPC</td>
</tr>
<tr>
<td></td>
<td>1066 or 1333 MHz</td>
<td>1066 or 1333 MHz</td>
<td>3 DPC</td>
</tr>
</tbody>
</table>
For example, a PowerEdge R610 with six 1333 MHz DIMMs (1 DPC) and the E5540 processor will run at 1066 MHz because the processor memory controller frequency is limited to 1066 MHz. Upgrading to an X5550 processor with a 1333 MHz memory controller will boost the operating memory frequency to 1333 MHz because all three requirements have been met.

The theoretical memory bandwidth for 1333 MHz memory is 25% faster than 1066 MHz memory. The micro-benchmark performance difference between DIMM speeds is bounded by this amount. Table 4 shows the measured micro-benchmark performance differences between DIMM of different speeds on a PowerEdge R410, with six 4GB RDIMMs and an X-series Xeon 5500 processor with a 1333 MHz memory controller.

**Table 4 – Micro-benchmark Performance - 1066MHz vs. 1333MHz**

<table>
<thead>
<tr>
<th>Benchmark</th>
<th>1333 MHz</th>
<th>1066 MHz</th>
<th>Relative Performance</th>
</tr>
</thead>
<tbody>
<tr>
<td>Stream - Triad</td>
<td>41286 GB/s</td>
<td>35676 GB/s</td>
<td>1.16</td>
</tr>
<tr>
<td>Lat_mem_rd</td>
<td>52.771 us</td>
<td>51.618 us</td>
<td>1.02</td>
</tr>
<tr>
<td>DGEMM</td>
<td>88.97 GFLOP/s</td>
<td>90.35 GFLOP/s</td>
<td>0.98</td>
</tr>
</tbody>
</table>

Table 4 shows a 16% memory bandwidth difference between 1333 and 1066 MHz DIMMs as measured by Stream. The memory latency and floating point rate benchmarks show a performance difference of only 1-2%. Therefore, although the theoretical memory bandwidth difference between the DIMM speeds is 25%, single server and clustered applications should show no more than 16% performance improvement with the faster DIMMs.

*Figure 4 – Single node Performance - 1066MHz vs. 1333MHz, PowerEdge R610 with dual Intel Xeon X5550, six 2GB 1066 and 1333MHz UDIMMs*
Figure 4 shows the difference in application performance on a single PowerEdge R610 server. These tests were run with six 2GB UDIMMs at 1333 MHz and 1066 MHz. The data shows that 1333 MHz DIMMs perform better than 1066 MHz by up to 4% for all tests except Ansys V12cg-2 and HPL. For these two tests, the performance difference between 1333 MHz and 1066 MHz was within a percentage point and not statistically significant. As expected, memory bound applications including Eclipse benefit most from the faster memory with performance gains of ~6%.

1333MHz DIMMs perform better than 1066 MHz but also consume more power. Figure 5 evaluates the performance/power consumption tradeoff between DIMM speeds on a 16-node cluster. This figure charts the power consumption and performance decline of using 1066 MHz memory instead of 1333 MHz memory in all the nodes. Power consumption values lower than 1.0 indicates that 1066 MHz DIMMs consumed less power by the corresponding amount. For example, ECLIPSE-FOURMILL shows a Power Consumption value of .92 which means the 1066 MHz DIMMs consumed 8% less power than the 1333 MHz DIMMs. Performance values lower than 1.0 indicates the amount performance decreased with 1066MHz DIMMs.

Figure 5 also includes energy efficiency data denoted within the circles above the power and performance values. Energy efficiency is derived by dividing the performance by the power consumed. It is measured in units of performance/Watt. Higher values mean better energy efficiency. Improvements can be due to decreased power usage, increased performance, or both.

**Figure 5 – Cluster-level Performance - 1066MHz vs. 1333MHz, 16-node PowerEdge M610 cluster with dual Intel Xeon X5570, 6 * 4GB 1333 and 1066 MHz RDIMMs**

This figure shows that 1066 MHz DIMMs were 2 to-4% slower than 1333 MHz DIMMs across the four applications. 1066 MHz DIMMs consumed 6-9% less power than the 1333 MHz DIMMs. Because the
power consumption reductions were greater than the performance losses, cluster level energy efficiency increased by up to 5% with 1066 MHz DIMMs.

Although the theoretical and micro-benchmark performance differences between 1066 MHz and 1333 MHz DIMMs are sizeable, measured application performance differences were modest. Hence 1066 MHz DIMMs are recommended for all but the most memory intensive applications. This is particularly true for large clusters where the energy efficiency advantage of 1066 MHz DIMMs is expected to grow.

**Memory Population: 1 DPC versus 2 DPC**

Memory controller speed, DIMM frequency, and DIMM population combine to determine the operating memory speed for 11G servers. There are instances where equal system capacity can be achieved by populating 2 DPC or by using 1 DPC with double-capacity DIMMs. This section of the paper compares the performance and energy efficiency of populating 1DPC versus 2DPC at equal capacity in balanced configurations.

11G servers with the Xeon 5500 processors support three DDR-3 memory channels per processor socket. A “balanced” memory configuration has all three memory channels identically populated. For example, a dual-socket server with 6 identical DIMMs with 1DPC would be balanced. A server with 12 identical DIMMs and 2 DPC would also be balanced. Figure 6 depicts a balanced configuration with 1DPC and Figure 7 depicts a balanced configuration with 2DPC.

![Figure 6 – Balanced Memory at 1DPC](image1)

![Figure 7 – Balanced Memory at 2DPC](image2)

With Xeon 5500 series processors, balanced configurations provide the best performance and this is discussed further in the next section. All 1 DPC versus 2 DPC comparisons in this section are based on balanced configurations. Table 5 compares 1 DPC versus 2 DPC micro-benchmark results. The results were obtained on a PowerEdge R610, with dual Intel Xeon X5570, 1066 MHz RDIMM in six 4GB DIMM (1DPC) and 12 2GB DIMM (2DPC) configurations. Micro-benchmark performance across both population schemes are within 1%.

**Table 5 – Micro-benchmark Performance – 1 DPC versus 2 DPC**

<table>
<thead>
<tr>
<th>Benchmark</th>
<th>1 DPC</th>
<th>2 DPC</th>
<th>Perf Delta</th>
</tr>
</thead>
<tbody>
<tr>
<td>Stream - Triad</td>
<td>34549 GB/s</td>
<td>34369 GB/s</td>
<td>1.01</td>
</tr>
<tr>
<td>Lat_mem_rd</td>
<td>51.618 us</td>
<td>51.272 us</td>
<td>1.01</td>
</tr>
<tr>
<td>DGEMM</td>
<td>90346.54 GFLOP/s</td>
<td>90317.71 GFLOP/s</td>
<td>1.00</td>
</tr>
</tbody>
</table>
Although performance remained constant between population schemes at 1066 MHz, populating 2 DPC improves memory bandwidth at 1333 MHz. The difference is shown in Table 6.

Table 6 – Micro-benchmark memory bandwidth performance – 1 DPC versus 2 DPC @ 1333 MHz

<table>
<thead>
<tr>
<th>Benchmark</th>
<th>1 DPC</th>
<th>2 DPC</th>
<th>Perf Delta</th>
</tr>
</thead>
<tbody>
<tr>
<td>Stream - Triad</td>
<td>41864 GB/s</td>
<td>43594 GB/s</td>
<td>1.04</td>
</tr>
</tbody>
</table>

At 1333 MHz, 2 DPC memory bandwidth improves by 4% over 1 DPC. As shown in Table 4 and Figure 5, the 16% memory bandwidth improvement between 1066 and 1333 MHz DIMMs at 1 DPC helped cluster application performance by only 4%. Therefore, it is unlikely that the additional 4% bandwidth provided by 2 DPC at 1333 MHz will improve cluster level performance by more than an additional 1%. This modest improvement will come at the cost of additional power consumption. For these reasons, the 1 DPC versus 2 DPC performance comparison focused on 1066 MHz DIMMs.

Figure 8 compares single server application benchmark results between 1 DPC and 2 DPC memory configurations. Numbers higher than 1.0 mean 1 DPC outperformed 2 DPC by the corresponding amount.

![Single server - 1DPC vs 2DPC](image)

Figure 8 – Single server performance – 1 DIMM per channel vs. 2 DIMMs per channel, PowerEdge R610 with dual Intel Xeon X5570, 1066MHz RDIMMs, 6 * 4GB and 12 * 2GB

For the majority of the single server application benchmarks, the performance difference between 1 DPC and 2 DPC was within 1% up or down. Applications that showed differences greater than 1% across population schemes were within the expected deviation across benchmark runs.

Table 7 shows the power consumption differences during single server benchmarks across the two DIMM population schemes. 2 DPC consumed more power than 1 DPC across all four benchmarks. ECLIPSE – the most memory bound application of the four – consumed nearly 5% more power at 2 DPC than 1 DPC.
Table 7 – 1DPC and 2DPC power consumption

<table>
<thead>
<tr>
<th>Benchmark</th>
<th>1 DPC power (W)</th>
<th>2 DPC power (W)</th>
<th>Power delta</th>
</tr>
</thead>
<tbody>
<tr>
<td>Ansys Mechanical - V12sp5</td>
<td>308.15</td>
<td>317.61</td>
<td>2.98%</td>
</tr>
<tr>
<td>ECLIPSE - FOURMILL</td>
<td>319.34</td>
<td>334.43</td>
<td>4.51%</td>
</tr>
<tr>
<td>HPL</td>
<td>322.58</td>
<td>333.50</td>
<td>3.27%</td>
</tr>
<tr>
<td>Fluent – truck_poly_14m</td>
<td>319.41</td>
<td>324.56</td>
<td>1.59%</td>
</tr>
</tbody>
</table>

The performance differences between 1 DPC and 2 DPC at 1066 MHz were slight across both the micro-benchmarks and single server application benchmarks. From a performance standpoint, the population schemes are identical. 1 DPC consumed less power than 2 DPC across all of the server benchmarks. 2 DPC consumed 5% more power for the most memory intensive benchmark. Therefore, 1 DPC is more energy efficient than 2 DPC. 1 DPC also allows for future expansion. For these reasons, 1 DPC is the recommended population scheme for HPC cluster nodes with 1066 MHz DIMMs.

Memory Population: Balanced versus Unbalanced

As described in the previous section, a balanced memory configuration is one that has some multiple of six identical DIMMs populated evenly across both processor sockets. For example, a dual-socket server with 6 identical DIMMs, 1 DIMM per channel (DPC) using each of the three channels per socket would be in a balanced configuration. Similarly, a server with 12 identical DIMMs at 2 DPC would also be in a balanced configuration.

An unbalanced configuration is one where not all channels are populated, not populated similarly, or populated similarly but with different capacity DIMMs. For example, a dual-socket server with 8 DIMMs, 4 DIMMs per socket would have 2 DIMMs in the first channel and 2 DIMMs each in the other two channels and would be in an unbalanced configuration. With the Intel 5500 series, a balanced configuration provides the best performance, because of the memory interleaving patterns.

Memory interleaving maximizes memory performance by allowing the memory controller to efficiently load balance requests across memory channels. Memory interleaving organizes memory contents so that adjacent sections are physically located on different memory channels. Interleaving helps performance because DRAM needs to be “pre-charged.” If data is continually read from the same channel, pre-charging will introduce periodic contention. Interleaving memory across channels hides the pre-charging latency. Data is accessed from alternating channels, which allows pre-charging to occur while the memory is not being accessed. Pre-charging latency decreases as the number of interleaved channels grows. During power on, the server BIOS determines the optimal memory interleaving scheme depending on how the memory is populated.

This section of the study compares performance and energy efficiency across the three memory population schemes depicted in Figure 9. The left-most image depicts a processor socket populated with 1 DIMM per memory channel. This is a balanced configuration with one 3-way interleave. The middle image shows a processor socket with an additional DIMM in the first memory channel. This unbalanced
configuration is configured with two 2-way interleaves. The right-most processor socket has an unbalanced configuration with only two DIMMs configured in one 2-way interleave. In all three cases the server BIOS interleaves memory in a manner that allows similar performance for all memory regions.

Figure 9 – Memory interleaving in balanced and unbalanced configurations

Figure 10 shows the micro-benchmark performance difference between the balanced and unbalanced configurations depicted in Figure 9. Although Figure 9 depicts population schemes across single sockets, both server sockets were identically populated during this study.

Figure 10 – Memory bandwidth and latency in balanced and unbalanced configurations, Single PowerEdge M610 with dual Intel Xeon E5540, 4GB 1066MHz RDIMMs

The 6-DIMM memory bandwidth was higher than the unbalanced configurations’ memory bandwidth by 22 to 29%. The latency was within 1% across all three population schemes. Although both unbalanced configurations used two-way memory interleaving, the 4-DIMM bandwidth was 6% higher than the 8-DIMM bandwidth. The results are not pictured, but DGEMM showed no performance difference across DIMM population schemes, which is expected since DGEMM is floating point intensive and not memory sensitive.
In fact, populating memory in a balanced configuration is more critical to performance than adding faster speed DIMMs or more memory capacity. This is shown in Figure 11 where a balanced 6 DIMM 1066 MHz configuration is compared to a faster configuration that has 1333 MHz DIMMs and also more memory capacity with 8 DIMMs. Four application benchmarks were run on a single server. Figure 11 shows the relative performance of the two configurations. A value higher than 1.0 indicates the balanced configuration out-performed the faster unbalanced one by the corresponding amount. With the Fluent benchmarks, the balanced configuration performed better by 3-10%. Eclipse is a memory sensitive application and, in this case, the balanced configuration improved by almost 40% even with 25% less memory capacity and 20% slower DIMMs.

![Figure 11 – Relative performance of 1066 balanced versus 1333 unbalanced, Single PowerEdge R610 with dual Intel Xeon X5550, 2GB UDIMMs in 6 1066MHz and 8 1333MHz DIMM configurations](image)

Figure 12 plots the performance of the unbalanced configurations relative to the balanced configuration across four cluster applications. Values higher than 1.0 indicate the unbalanced configuration outperformed the balanced configuration by the corresponding amount. The circles above the bar graph depict the unbalanced configurations’ energy efficiency relative to the balanced configuration. Energy efficiency is calculated by dividing the application performance by average Watts consumed during the application run. A value greater than 1.00 indicates that the unbalanced configuration was more energy efficient than the balanced.
Figure 12 – Cluster level performance in balanced and unbalanced configurations, 16-node PowerEdge M610 cluster with dual Intel Xeon E5540 processors, 4GB 1333 MHz RDIMMs in 4, 6 and 8DIMM configurations

The memory bandwidth micro-benchmark results showed that balanced configurations outperform unbalanced configurations by 22-29%. This result was confirmed by the application benchmark results. Eclipse was the most memory bound application tested. Eclipse performance declined by 15 and 23% when run on unbalanced nodes. The 8-DIMM configuration was almost 10% slower than the 4-DIMM configuration. The three other cluster applications tested showed a 4-12% performance decline. Therefore, from a performance standpoint, balanced configurations outperform unbalanced configurations at the cluster level. The performance difference is not as great across clustered applications as it is across the micro-benchmark results.

The energy efficiency of the unbalanced configurations also suffered. For 4-DIMM configurations the energy efficiency declined despite the fact that 4 DIMMs consume less power than 6 DIMMs. The lower power consumption of the 4 DIMM configurations did not offset the performance decline. Fluent was a notable exception. Fluent performance decreased by less than 5% with the 4-DIMMs across unbalanced configurations. The slight performance drop combined with lower power consumption to improve the energy efficiency of the 4DIMM configuration by 5%. For Fluent, the 8-DIMM energy efficiency matched the 6-DIMM energy efficiency because both the performance decline and power consumption increase were small. The energy efficiency of the 8-DIMM configurations declined by 12-16% when running the
other three cluster applications due to the combined effects of the performance decrease and increased power consumption.

Based on these results, a balanced configuration is recommended for general purpose HPC workloads. Unbalanced configurations suffer in terms of performance and energy efficiency. The unbalanced 4-DIMM configuration is a viable option for HPC workloads that are not memory sensitive because it can reduce power consumption and lower acquisition cost. The 8-DIMM unbalanced configuration suffers in terms of performance, energy efficiency, and acquisition cost.

**Conclusion**

PowerEdge 11G servers feature a modular architecture that allows users to select components ideally suited for their needs. However, users are often unsure of how these selections will impact their application performance. The Dell HPC engineering team evaluated the performance and power consumption of 11G servers running various HPC workloads across several memory configurations in order to simplify the memory selection process. Based on the results of this study, the Dell HPC engineering team recommends the following configurations for maximizing performance, maximizing energy efficiency, and minimizing power consumption.

<table>
<thead>
<tr>
<th>Usage Model</th>
<th>Processor Family</th>
<th>DIMM Type</th>
<th>DIMM Speed</th>
<th>DIMM Count</th>
<th>DIMM Population</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>Performance</strong></td>
<td>X-series</td>
<td>UDIMM</td>
<td>1333</td>
<td>12</td>
<td>Balanced, 3 per socket</td>
</tr>
<tr>
<td><strong>Energy Efficiency</strong></td>
<td>E-series</td>
<td>UDIMM</td>
<td>1066</td>
<td>6</td>
<td>Balanced, 3 per socket</td>
</tr>
<tr>
<td><strong>Power</strong></td>
<td>L-series</td>
<td>UDIMM</td>
<td>1066</td>
<td>4</td>
<td>Unbalanced, 2 per socket</td>
</tr>
</tbody>
</table>

Cost and capacity are two additional considerations that have not been discussed in this paper. In general, the minimum required capacity per core should be the starting point for memory selection. In the past, the typical HPC customer required 2 GB of memory per core. For 11G servers, 3 GB per core maximizes performance and energy efficiency because this requirement can be met by several balanced configurations.

Cost is another primary concern for HPC customers. The cost of purchasing high speed, high capacity DRAM in large quantities can offset a cluster’s favorable economy of scale. Furthermore, HPC customers do not typically exploit the reliability features afforded by RDIMMs. In general, the decision to buy faster DIMMs is justified if the percentage of performance improvement when executing the most frequently used application exceeds the percentage of cost increase. In terms of capacity, buying the highest capacity DIMMs within budget and using fewer DIMM slots is recommended. This allows the system to run at the fastest memory speed while also allowing for future memory expansion.

Finally, it is also important to consider that the power consumption differences between DIMM types and population schemes at equal capacity will be magnified by the cluster size. When selecting memory
for hundreds or thousands of servers, the small power savings associated with purchasing 1 DPC rather than 2 DPC may save thousands of dollars over the machine’s lifetime.

References

1. Data Center Workhorses: New Dell PowerEdge Rack and Blade Servers

2. DDR3
   http://en.wikipedia.org/wiki/DDR3_SDRAM

3. Intel Xeon 5500 series Memory controller bandwidth

4. Intel QuickPath Interconnect

5. Optimal BIOS Settings for High Performance Computing with PowerEdge 11G Servers

6. Dell PowerEdge M610 BIOS Version 1.2.7 RELEASE NOTES
   http://ftp.us.dell.com/bios/R610-010206BIOS.txt
Appendix A – Summary of Key Findings

1. DIMM frequency is limited by the processor’s memory controller frequency. Do not buy faster DIMMs than the memory controller can run. Refer to page 10.

2. RDIMMs and UDIMMs have equal performance but UDIMMs consume less power. Refer to Figure 3 and Table 2.

3. For clustered benchmarks, the 1333 MHz DIMMs outperformed 1066 MHz DIMMs by less than 5% on average. Refer to Figure 5.

4. 1333 MHz DIMMs consumed 6-9% more power than 1066 DIMMs and were 5% less energy efficient. Refer to Figure 5.

5. Most PowerEdge 11G servers support 2 DPC at 1333 MHz provided the CPU memory controller can run at 1333 MHz. Refer to page 10.

6. At equal capacities and 1066 MHz, populating 2 DPC consumes 5% more power than 1 DPC but does not improve application performance. Refer to Figure 8, Table 5 and Table 7.

7. At 1333 MHz, 2 DPC memory bandwidth is 4% higher than at 1 DPC. This is expected to result in ~1% performance improvement at the cluster level for bandwidth sensitive applications. Refer to Table 6.

8. Table 6.

9. Balanced configurations outperform unbalanced configurations by 4-23% when running clustered applications. Refer to Figure 12.

10. A balanced 1066 MHz DIMM configuration will outperform an unbalanced 1333 MHz configuration. Refer to Figure 11.

11. The 4-DIMM unbalanced configuration outperforms the 8-DIMM unbalanced configuration by up to 10% on memory intensive applications. Refer to Figure 12.

12. For some CPU-intensive applications, unbalanced 4-DIMM configurations can reduce power consumption and cost without a significant performance decline. Refer to Figure 12.
# Appendix B - Test Cluster

<table>
<thead>
<tr>
<th>Component</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>SERVERS:</td>
<td>Dell PowerEdge R610, Dell PowerEdge M610 (16) in a PowerEdge M1000e chassis</td>
</tr>
<tr>
<td>SERVER BIOS:</td>
<td>1.1.4, 1.2.6</td>
</tr>
<tr>
<td>PROCESSORS:</td>
<td>Intel Xeon X5550, Intel Xeon X5570, Intel Xeon E5540</td>
</tr>
<tr>
<td>MEMORY:</td>
<td>6 x 4GB 1333 MHz RDIMM, 6 x 4GB 1066 MHz RDIMM, and as noted.</td>
</tr>
<tr>
<td>STORAGE:</td>
<td>Dell SAS 6iR controller, 2 x 73GB 10k RPM SAS hard drives, RAID 1 on M610</td>
</tr>
<tr>
<td></td>
<td>Dell Perc6i controller, 2 x 73GB 15k RPM SAS hard drives, RAID 0 on R610</td>
</tr>
<tr>
<td>INTERCONNECT:</td>
<td>InfiniBand - Mellanox MTH MT26428 [ConnectX IB QDR, Gen-2 PCIe]</td>
</tr>
<tr>
<td>IB SWITCH:</td>
<td>Mellanox 3601Q QDR blade chassis I/O switch module</td>
</tr>
<tr>
<td>GbE NETWORK:</td>
<td>Broadcom BCM5709</td>
</tr>
<tr>
<td>GbE switch:</td>
<td>PowerConnect M6220 blade chassis I/O switch module, PowerConnect 6248 rack</td>
</tr>
<tr>
<td></td>
<td>switch</td>
</tr>
<tr>
<td>SOFTWARE:</td>
<td>ClusterCorp Rocks+ 5.1 for Dell*³</td>
</tr>
<tr>
<td>OS:</td>
<td>Red Hat Enterprise Linux 5.3 x86_64 (2.6.18-128.el5 kernel)</td>
</tr>
<tr>
<td>IB STACK:</td>
<td>Mellanox OFED 1.4</td>
</tr>
</tbody>
</table>

*This product includes software developed by the Rocks Cluster Group at the San Diego Supercomputer Center at the University of California, San Diego and its contributors.
Appendix C – Benchmark Descriptions

<table>
<thead>
<tr>
<th>Benchmark</th>
<th>Description</th>
<th>Type</th>
</tr>
</thead>
<tbody>
<tr>
<td>Stream¹</td>
<td>Threaded memory bandwidth test</td>
<td>Memory micro-benchmark</td>
</tr>
<tr>
<td>lat_mem_rd²</td>
<td>Memory latency test. Idle array chasing</td>
<td>Memory micro-benchmark from LMBench</td>
</tr>
<tr>
<td>DGEMM³</td>
<td>Threaded matrix multiplication routine</td>
<td>CPU micro-benchmark</td>
</tr>
<tr>
<td>HPL⁴</td>
<td>Distributed floating point benchmark</td>
<td>CPU and communication benchmark</td>
</tr>
<tr>
<td>Fluent⁵</td>
<td>Computational fluid dynamics</td>
<td>Commercial clustered application</td>
</tr>
<tr>
<td>Ansys⁶</td>
<td>Structural mechanics</td>
<td>Commercial clustered application</td>
</tr>
<tr>
<td>ECLIPSE⁷</td>
<td>Reservoir simulation.</td>
<td>Commercial clustered application</td>
</tr>
<tr>
<td>WRF⁸</td>
<td>Climate modeling</td>
<td>Open source clustered application</td>
</tr>
<tr>
<td>LU⁹</td>
<td>Lower-upper decomposition physical systems</td>
<td>Open source clustered synthetic kernel</td>
</tr>
</tbody>
</table>

9. LU: NAS Parallel Benchmarks. NPB-MPI v3.3, LU class D.: [https://www.nas.nasa.gov/cgi-bin/software/start](https://www.nas.nasa.gov/cgi-bin/software/start)